

AMENDMENTS TO THE CLAIMS

1. (Cancelled).

2. (Currently Amended) The surface acoustic wave device of Claim 13, wherein the said surface acoustic wave element further ~~comprising~~comprises a connection pattern ~~which connects~~configured to connect an earth terminal pattern of either ~~the said~~ first filter structure or ~~the said~~ second filter structure to ~~the said~~ shield electrode.

3. (Currently amended) ~~The~~ A surface acoustic wave device ~~of Claim 1,~~including a structure in which a surface acoustic wave element provided with two kinds of surface acoustic wave filter structures having different center frequencies on a same piezoelectric substrate is disposed on a package, said surface acoustic wave element comprising:

a first filter structure having a first center frequency;

a second filter structure having a second center frequency;

a shield electrode positioned between said first filter structure and said second filter structure, said shield electrode being connected to an earth terminal of the package to be grounded in which and comprising the shield electrode has a first shield electrode and a second shield electrode;

~~the surface acoustic wave element further comprising:~~

a first connection pattern ~~which connects~~configured to connect an earth terminal pattern of ~~the said~~ first filter structure to ~~the said~~ first shield electrode; and

a second connection pattern ~~which connects~~configured to connect an earth terminal pattern of ~~the said~~ second filter structure to ~~the said~~ second shield electrode.

4. (Cancelled).

5. (Currently amended) The surface acoustic wave device of Claim 13,

wherein the said shield electrode is formed to be longer than the said first filter structure and the said second filter structure so as to segment the said first filter structure and the said

second filter structure.

6. (Currently amended) ~~The~~ A surface acoustic wave device of Claim 4, ~~including a structure in~~ which a surface acoustic wave element provided with two kinds of surface acoustic wave filter structures having different center frequencies on a same piezoelectric substrate is disposed on a package, said surface acoustic wave element comprising:

a first filter structure having a first center frequency;

a second filter structure have a second center frequency;

a shield electrode positioned between said first filter structure and said second filter structure, said shield electrode being connected to an earth terminal of the package to be grounded; and

a pattern in which said shield electrode is configured to cross a signal wire lead connecting at least one signal line terminal pattern in said first filter structure and said second filter structure to a signal terminal of the package,

wherein said shield electrode is connected to earth terminals of the package by at least two earth wire leads ~~wherein the two earth wire leads connecting the shield electrode to earth terminals of the package~~ that are arranged at both sides of the signal wire lead connecting the signal line terminal pattern to the signal terminal of the package.

7-8. (Cancelled).

9. (Currently amended) The surface acoustic wave device of Claim 8 ~~10~~, wherein ~~the said~~ first filter structure and ~~the said~~ second filter structure are ladder circuits ~~connecting configured to connect~~ one-terminal surface acoustic wave resonators in series arms and in parallel arms, and a surface acoustic wave resonator which is nearest to the said second filter structure in the said first filter structure having a relatively low center frequency is a parallel arm, and a surface acoustic wave resonator which is nearest to the said first filter structure in the said second filter structure is a series arm.

10. **(Currently amended)** ~~The~~ A surface acoustic wave device ~~of Claim 8,~~ including a structure in which a surface acoustic wave element provided with two kinds of surface acoustic wave filter structures having different center frequencies on a same piezoelectric substrate is disposed on a package, said surface acoustic wave element comprising:

a first filter structure having a first center frequency;

a second filter structure having a second center frequency; and

a shield electrode positioned between said first filter structure and said second filter structure, said shield electrode being connected to an earth terminal of the package to be grounded,

wherein said first filter structure, said second filter structure and said shield electrode are disposed in a vertical direction to a propagation direction of surface acoustic waves of said first filter structure and said second filter structure, and

wherein ~~the~~ said shield electrode has a grating shape including plural slits in a vertical direction relative to comb-shaped electrodes in ~~the~~ said first filter structure and ~~the~~ said second filter structure.

11. **(Cancelled).**

12. **(Currently amended)** ~~The~~ A surface acoustic wave device ~~of Claim 11,~~ including a structure in which a surface acoustic wave element provided with two kinds of surface acoustic wave filter structures having different center frequencies on a same piezoelectric substrate is disposed on a package, said surface acoustic wave element comprising:

a first filter structure having a first center frequency;

a second filter structure having a second center frequency; and

a shield electrode positioned between said first filter structure and said second filter structure, said shield electrode being connected to an earth terminal of the package to be grounded;

wherein said first filter structure and said second filter structure are disposed in parallel to a propagation direction of surface acoustic waves of said first filter structure and said second filter structure, and said shield electrode is disposed in a vertical direction to the propagation

direction of surface acoustic waves, and

wherein ~~the~~said shield electrode has a grating shape including plural slits in a parallel direction relative to comb-shaped electrodes in ~~the~~said first filter structure and ~~the~~said second filter structure.

13. (Currently amended) The surface acoustic wave device of Claim ~~8~~10, wherein ~~the~~said shield electrode has a grating shape including plural slits in an oblique direction to a propagation direction of surface acoustic ~~wave~~waves in ~~the~~said first filter structure and ~~the~~said second filter structure.

14. (Previously presented) The surface acoustic wave device of Claim 10, wherein the slits of ~~the~~said shield electrode are formed by pitches between ~~the~~a minimum pitch and ~~the~~a maximum pitch of comb-shaped electrodes included in ~~the~~said first filter structure and ~~the~~said second filter structure.

15. (Previously presented) The surface acoustic wave device of Claim 10, wherein the slits of ~~the~~said shield electrode are formed by different pitches depending on positions.

16-17. (Cancelled).

18. (Currently amended) The surface acoustic wave device of Claim ~~13~~13, wherein ~~the~~said first filter structure and ~~the~~said second filter structure are, respectively, a transmission filter and a reception filter, and the transmission filter and the reception filter ~~forms~~form a surface acoustic wave duplexer.

19. (Currently amended) The surface acoustic wave device of claim 18, wherein ~~the~~a signal line terminal pattern is an input/output terminal pattern of either the transmission filter or the reception filter.

- 20. (New)** The surface acoustic wave device of Claim 6,
wherein said shield electrode is formed to be longer than said first filter structure and said second filter structure to segment said first filter structure and said second filter structure.
- 21. (New)** The surface acoustic wave device of Claim 6, wherein said first filter structure and said second filter structure are, respectively, a transmission filter and a reception filter, and the transmission filter and the reception filter form a surface acoustic wave duplexer.
- 22. (New)** The surface acoustic wave device of claim 21, wherein a signal line terminal pattern is an input/output terminal pattern of either the transmission filter or the reception filter.
- 23. (New)** The surface acoustic wave device of Claim 10, wherein said shield electrode is formed to be longer than said first filter structure and said second filter structure to segment said first filter structure and said second filter structure.
- 24. (New)** The surface acoustic wave device of Claim 10, wherein said first filter structure and said second filter structure are, respectively, a transmission filter and a reception filter, and the transmission filter and the reception filter form a surface acoustic wave duplexer.
- 25. (New)** The surface acoustic wave device of claim 24, wherein a signal line terminal pattern is an input/output terminal pattern of either the transmission filter or the reception filter.
- 26. (New)** The surface acoustic wave device of Claim 12, wherein said shield electrode is formed to be longer than said first filter structure and said second filter structure to segment said first filter structure and said second filter structure.
- 27. (New)** The surface acoustic wave device of Claim 12, wherein said first filter structure and said second filter structure are, respectively, a transmission filter and a reception filter, and the transmission filter and the reception filter form a surface acoustic wave duplexer.

28. (New) The surface acoustic wave device of claim 27, wherein a signal line terminal pattern is an input/output terminal pattern of either the transmission filter or the reception filter.